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20A, 45V - 60V Low V_F Trench Schottky Rectifier

FEATURES

- Patented Trench Schottky technology
- Excellent high temperature stability
- Low forward voltage
- Low power loss/ High efficiency
- High forward surge capability
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- DC to DC converters

MECHANICAL DATA

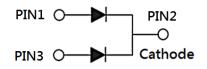
- Case: TO-220AB
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Mounting torque: 0.56 N⋅m maximum
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 1.88g (approximately)

| KEY PARAMETERS | | |
|--------------------|----------|------|
| PARAMETER | VALUE | UNIT |
| I _F | 20 | А |
| V _{RRM} | 45 - 60 | V |
| I _{FSM} | 120 | А |
| T _{J MAX} | 150 | °C |
| Package | TO-220AB | |
| Configuration | Dual d | lies |





TO-220AB



| ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted) | | | | |
|--|---------------------|-------------|-----------|------|
| PARAMETER | SYMBOL | TST20U45C | TST20U60C | UNIT |
| Marking code on the device | | TST20U45C | TST20U60C | |
| Repetitive peak reverse voltage | V _{RRM} | 45 | 60 | V |
| Reverse voltage, total rms value | V _{R(RMS)} | 31 | 42 | V |
| Forward current | I _F | 2 | 0 | Α |
| Surge peak forward current, 8.3ms single half sine wave superimposed on rated load | I _{FSM} | 120 | | А |
| Critical rate of rise of off-state voltage | dv/dt | 10,000 | | V/µs |
| Junction temperature | TJ | -55 to +150 | | °C |
| Storage temperature | T _{STG} | -55 to +150 | | °C |



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| THERMAL PERFORMANCE | | | | |
|-------------------------------------|-----------|------------------|-----|------|
| PARAMETER | | SYMBOL | ТҮР | UNIT |
| lunction to cope thermal resistance | TST20U45C | R _{eJC} | 2 | °C/W |
| Junction-to-case thermal resistance | TST20U60C | | 2.4 | °C/W |

| ELECTRICAL SPECIFI | CATIONS | (T _A = 25°C unless othe | rwise noted) | | | |
|--|-----------|------------------------------------|------------------|------|------|------|
| PARAMETER | | CONDITIONS | SYMBOL | ТҮР | MAX | UNIT |
| Forward voltage per diode ⁽¹⁾ | TST20U45C | $I_F = 10A, T_J = 25^{\circ}C$ | V _F | - | 0.53 | V |
| | TST20U60C | | | - | 0.54 | V |
| | TST20U45C | $I_F = 20A, T_J = 25^{\circ}C$ | | - | 0.60 | V |
| | TST20U60C | | | - | 0.63 | V |
| | TST20U45C | $I_F = 10A, T_J = 125^{\circ}C$ | | 0.39 | 0.44 | V |
| | TST20U60C | | | 0.43 | 0.48 | V |
| | TST20U45C | $I_F = 20A, T_J = 125^{\circ}C$ | | - | 0.55 | V |
| | TST20U60C | | | - | 0.61 | V |
| Reverse current @ rated V_R per diode ⁽²⁾ | | $T_J = 25^{\circ}C$ | - I _R | - | 300 | μA |
| | | T _J = 125°C | | - | 60 | mA |

Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms

| ORDERING INFORMATION | | |
|------------------------------|----------|-----------|
| ORDERING CODE ⁽¹⁾ | PACKAGE | PACKING |
| TST20UxC | TO-220AB | 50 / Tube |

Notes:

1. "x" defines voltage from 45V(TST20U45C) to 60V(TST20U60C)



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CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

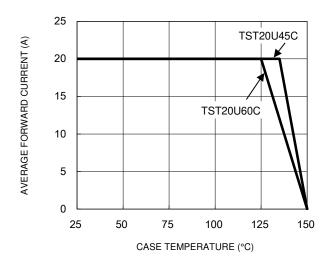
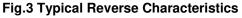
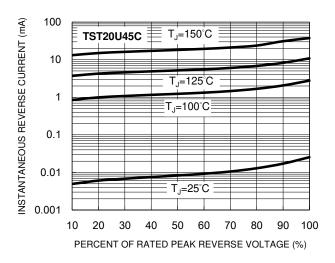
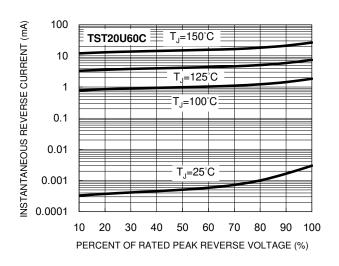


Fig.1 Forward Current Derating Curve









(g) 1000 1.00 1.00 1.00 1.00 10.00 10.00

Fig.2 Typical Junction Capacitance

Fig.4 Typical Forward Characteristics

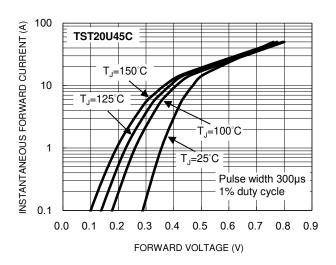
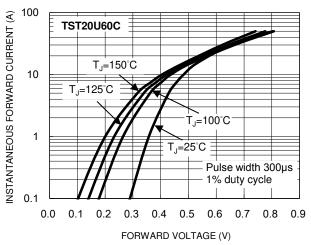


Fig.6 Typical Forward Characteristics

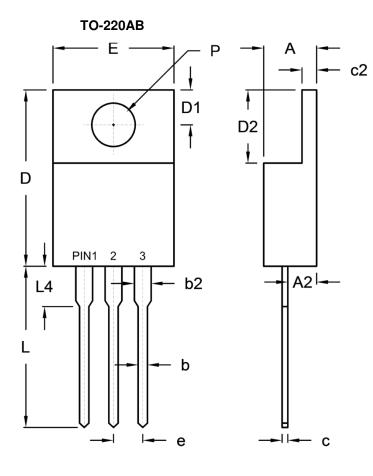




TST20U45C – TST20U60C

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PACKAGE OUTLINE DIMENSIONS



| DIM. | Unit (mm) | | Unit (| it (inch) | |
|------|-----------|-------|--------|-----------|--|
| | Min. | Max. | Min. | Max. | |
| A | 4.42 | 4.76 | 0.174 | 0.187 | |
| A2 | 2.20 | 2.80 | 0.087 | 0.110 | |
| b | 0.68 | 0.94 | 0.027 | 0.037 | |
| b2 | 1.14 | 1.77 | 0.045 | 0.070 | |
| с | 0.35 | 0.64 | 0.014 | 0.025 | |
| c2 | 1.14 | 1.40 | 0.045 | 0.055 | |
| D | 14.60 | 16.00 | 0.575 | 0.630 | |
| D1 | 2.62 | 3.44 | 0.103 | 0.135 | |
| D2 | 5.84 | 6.86 | 0.230 | 0.270 | |
| E | - | 10.50 | - | 0.413 | |
| е | 2.41 | 2.67 | 0.095 | 0.105 | |
| L | 13.19 | 14.79 | 0.519 | 0.582 | |
| L4 | 2.80 | 4.20 | 0.110 | 0.165 | |
| Р | 3.54 | 4.00 | 0.139 | 0.157 | |

MARKING DIAGRAM



| P/N | = Marking Code |
|-----|------------------|
| G | = Green Compound |
| YWW | = Date Code |
| F | = Factory Code |



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